JL6976M Datasheet

Zhuhai Jieli Technology Co.,LTD

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JL6976M Features

CPU

- 32-bit DSP supports hardware Float Point Unit(FPU)
- Up to 160MHz programmable processor
- 64Vectored interrupts
- 4 Levels interrupt priority

DSP Audio Processing

- SBC, AAC Audio decodes supported for BT audio
- mSBC voice codec supported for BT phone
- Supports MP2, MP3, WMA, APE, FLAC, AAC, MP4, M4A, WAV, AIF, AIFC audio decoding
- Packet Loss Concealment (PLC) for voice processing
- Acoustic echo cancellation/suppression (AEC,AES)
- Single/Dual MIC Environmental Noise Cancellation (ENC)
- Multi-band DRC limiter
- 20-band EQ configuration for voice Effects

Audio Codec

- Two channels 24-bit DAC, SNR >= 101dB
- Two channels 24-bit ADC, SNR >= 92dB
- Sampling rates of 8KHz/11.025KHz/16KHz/22.05KHz/24KHz/32KHz/44.1KHz/48KHz are supported
- Two analog MIC amplifier, build-in MIC bias generator
- Supports two PDM digital MIC inputs
- One channel Stereo analog MUX
- Supports cap-less, single-ended, and differential mode at the DAC path
- Supports 16ohm and 32ohm Speaker loading

Bluetooth

Compliant with Bluetooth

- V5.3+BR+EDR+BLE specification
- Meet class2 and class3 transmitting power requirement
- Support GFSK and π/4 DQPSK all packet types
- Provides amaximum+8dbm transmitting power
- receiver with -94dBm sensitivity
- Fast AGC for enhanced dynamic range
- Supports

 a2dp\avctp\avdtp\avrcp\hfp\spp\smp\att\gap
 \gatt\rfcomm\sdp\l2cap profile
- a2dp 1.3.2\avctp 1.4\avdtp 1.3\ avrcp 1.6.2\ hfp 1.8 \spp 1.2\rfcomm 1.1\pnp 1.3\ hid 1.1.1\sdp core5.3\l2cap core 5.3

Peripherals

- One full speed USB 2.0 OTG controller
- Six multi-function 32-bit timers, support capture and PWM mode
- Three full-duplex basic UART, support DMA mode
- One hard ware IIC interface supports host and device mode
- Built-in Cap Sense Key controller
- Two Built-in low power Cap Sense Keys
- 10-bit ADC for analog sampling
- External wake up/interrupt on all GPIOs

PMU

- Low voltage LDO and DC-DC for internal digital and analog circuit supply
- 2uA current consumption in the soft-off mode
- Built-in LDO and DC-DC for the core, I/O, Bluetooth and flash
- VBAT is 2.2V to 4.5V
- VDDIO is 2.2V to 3.4V

Packages

QFN32(4mm*4mm)

2

Temperature

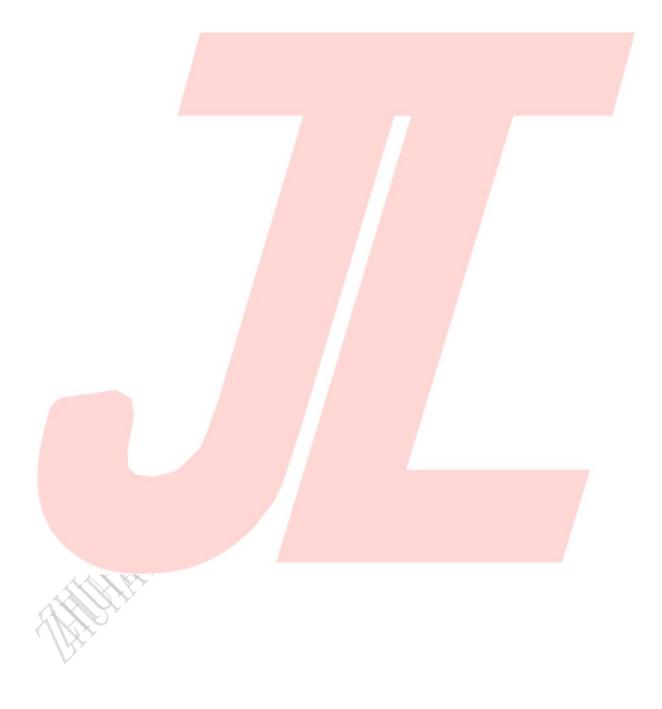
• Operating temperature: -40°C to +85°C

Storage temperature: -65° C to $+150^{\circ}$ C

Applications

Bluetooth wireless MIC

Bluetooth Game Earphone



1. Pin Definition

1.1 Pin Assignment

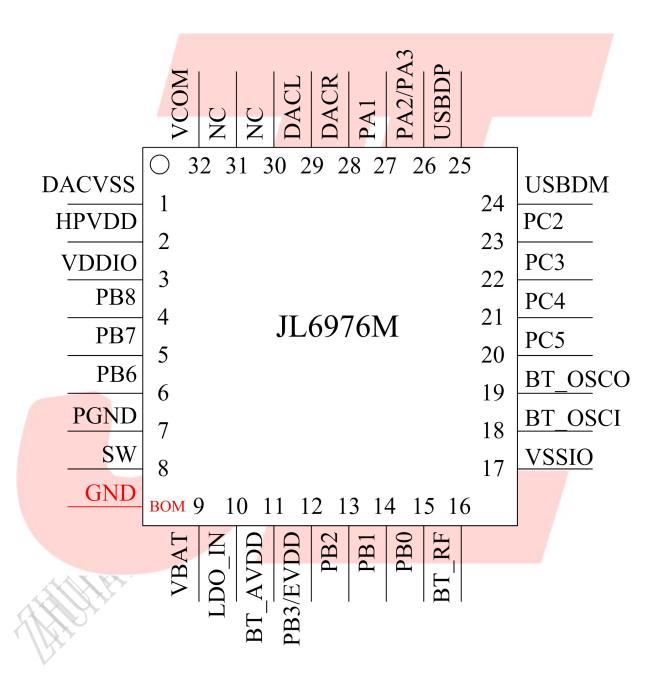


Figure 1-1 JL6976M Package Diagram

1.2 Pin Description

Table 1-1 JL6976M Pin Description

PIN NO.	Name	I/O Type	Drive (mA)	Function	Other Function
1	DACVSS	P	/		Analog Ground
2	HPVDD	P	/	/	Headphone AMP Power
3	VDDIO	P	/		IO Power 3.3v
4	PB8	I/O	8/24	GPIO	MIC1: MIC1 Input Channel; UART0RXB: Uart0 Data Input(B); CAP4: Timer4 Capture;
5	PB7	I/O	8/24	GPIO	MIC_BIAS1: MIC1 Bias Output; UART0TXB: Uart0 Data Output(B);
6	PB6	I/O	8/24	GPIO	UART1RXA: Uart1 Data Input(A); PWM2: Timer2 PWM Output; ADC9: ADC Input Channel 9; Touch7: Touch Input Channel 7;
7	PGND	P	/		DCDC Ground
8	SW	P	/		DCDC switch output, connected to inductor
9	VBAT	P	/	100	Power Supply, connect to battery
10	LDO_IN	P	1		Charge Power Input; UART0TXC: Uart0 Data Output(C); UART0RXC: Uart0 Data Input(C); PWM3: Timer3 PWM Output; CAP1: Timer1 Capture;
11	BT_AVDD	P	1	GPIO	BT Power
	PB3	I/O	8/24	GPIO	
12	EVDD	P	/		EVDD: Supply volte to peripherals
13	PB2	I/O	8/24	GPIO	UART2RXC: Uart2 Data Input(C); SPI2DOC: SPI2 Data Out(C); CAP5: Timer5 Capture; ADC7: ADC Input Channel 7; LP_TH1: Low Power Touch Channel 1
14	PB1	I/O	8/24	GPIO (pull up)	Long Press Reset; SPI2CLKC: SPI2 Clk(C); UART2TXC: Uart2 Data Output(C) ADC6: ADC Input Channel 6; LP_TH0: Low Power Touch Channel 0

15	РВ0	I/O	8	GPIO (High Voltage Input)	SPI2_DIC: SPI2 Data In(C); ALNK_MCLK(B): ALNK1 Master Clock(B); TMR4: Timer4 Clock Input;
16	BT_RF	/	/		BT Antenna
17	VSSIO	P	/		Ground
18	BT_OSCI	I	/		BTOSC In
19	BT_OSCO	О	/		BTOSC Out
20	PC5	I/O	8/24	GPIO	UART2RXD: Uart2 Data Input(D); SPI1DOB: SPI1 Data Out(B); ALNK_DAT3(B): Audio Link Data3(B); IIC_SDA_B: IIC SDA(B); ADC5: ADC Input Channel 5;
21	PC4	I/O	8/24	GPIO	UART2TXD: Uart2 Data Output(D); SPI1CLKB: SPI1 Clock(B); ALNK_DAT2(B): Audio Link Data2(B); IIC_SCL_B: IIC SCL(B); ADC4: ADC Input Channel 4; PWM4: Timer4 PWM Output;
22	PC3	I/O	8/24	GPIO	UARTORXD: Uarto Data Input(D); SPI1DIB: SPI1 Data In(B); ALNK_LRCK(B): Audio Link Word Select(B); IIC_SDA_C: IIC SDA(C); TMR3: Timer3 Clock Input;
23	PC2	I/O	8/24	GPIO	ALNK_SCLK(B): Audio Link Serial Clock(B); IIC_SCL_C: IIC SCL(C); UART0TXD: Uart0 Data Output(D); TMR1: Timer1 Clock Input;
24	USBDM	I/O	4	USB Negative Data	UART1RXD: Uart1 Data Input(D); IIC_SDA_A: IIC SDA(A); ADC11: ADC Input Channel 11;
25	USBDP	I/O	4	USB Positive Data	UART1TXD: Uart1 Data Output(D); IIC_SCL_A: IIC SCL(A); ADC10: ADC Input Channel 10;
	PA3	I/O	8/24	GPIO	UART2TXA: Uart2 Data Output(A); ADC0: ADC Input Channel 0; PWM1: Timer1 PWM Output; Touch0: Touch Input Channel 0;
26	PA2	I/O	8/24	GPIO	ALNK_MCLK(A): ALNK Master Clock(A); MIC_BIASO: MIC0 Bias Output; MIC0_N: Different MIC0 Negative CAP3: Timer3 Capture;

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					UART1RXC: Uart1 Data In(C);	
27	PA1	I/O	8/24	GPIO	MIC0: MIC0 Input Channel; PWM0: Timer0 PWM Output; UART1TXC: Uart1 Data Output(C);	
28	DACR	О	/		DAC Right Channel	
29	DACL	О	/		DAC Left Channel	
30	NC					
31	NC	/				
32	VCOM	P	/		DAC reference voltage	



2. Electrical Characteristics

2.1 Absolute Maximum Ratings

Table 2-1

Symbol	Parameter	Min	Max	Unit
Topt	Operating temperature	-40	+85	°C
Tstg	Storage temperature	-65	+150	°C
VBAT	Supply Voltage	-0.3	4.5	V
LDO_IN	Charger Voltage	-0.3	6	V
V _{3.3IO}	3.3V IO Input Voltage	-0.3	3.6	V

Note: The chip can be damaged by any stress in excess of the absolute maximum ratings listed below

2.2 PMU Characteristics

Table 2-2

Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
VBAT	Voltage Input	2.2	3.7	4.2	V	
	Charger supply	1				
LDO_IN	Voltage	4.5	5.0	5.5	V	
Normal mode						
VDDIO	Voltage output	-	3.0	I	V	VBAT = 4.2V, 10mA loading
VDDIO	Loading current	_	4/	100	mA	VDDIO=3V@VBAT = 4.2V
BT AVDD	Voltage output	_	1.3	1	V	VDDIO=3.0V, 10mA loading
BI_AVDD	Loading current	-		60	mA	BT_AVDD=1.25V@VDDIO=3.0v
EVDD	Voltage output	-	1.1	1	V	BT_AVDD=1.25V, 1mA loading
EADD	Loading current	Silve Market	I	5	mA	EVDD=1.1V@BT_AVDD=1.25v
LP mode						
VDDIO	Loading current			5	mA	VDDIO=3V@VBAT = 4.2V

2.3 Battery Charge

Table 2-3

Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
LDO_IN	Charge Input Voltage	4.5	5	5.5	V	_
V_{Charge}	Charge Voltage	4.15	4.2	4.25	V	LDO_IN>4.5V

		4.30	4.35	4.40	V	LDO_IN>4.65V
I_{Charge}	Charge Current	20		200	mA	Charge current at fast charge mode
I_{Trikl}	Trickle Charge Current	20	45	70	mA	$V_{\mathrm{BAT}} \!\!<\!\! V_{\mathrm{Trikl}}$

2.4 IO Input/Output Electrical Logical Characteristics

Table 2-4

IO input ch	aracteristics		<u> </u>			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
V _{IL}	Low-Level Input Voltage	-0.3	-	0.3* VDDIO	V	VDDIO = 3.3V
$ m V_{IH}$	High-Level Input Voltage	0.7* VDDIO	-	VDDIO+0.3	V	VDDIO = 3.3V
IO output o	characteristics			7 /	syl	
$V_{ m OL}$	Low-Level Output Voltage	_	-	0.33	V	VDDIO = 3.3V
V _{OH}	High-Level Output Voltage	2.7	- /	A -	V	VDDIO = 3.3V

2.5 Internal Resistor Characteristics

Table 2-5

			Tubie		
Port	General Output	High Drive	Internal Pull-Up Resistor	Internal Pull-Down Resistor	Comment
PA1~PA3 PC2~PC5 PB3~PB3 PB6~PB8	8mA	24mA	10K	10K	1、PB1 default pull up 2、USBDM & USBDP default pull
PB0	8mA	-	10K	10K	down 3 internal pull-up/pull-down
USBDP	4mA	_	1.5K	15K	resistance accuracy ±20%
USBDM	4mA	_	180K	15K	

2.6 DAC Characteristics

Table 2-6

Parameter	Min	Тур	Max	Unit	Test Conditions
Frequency Response	20	_	20K	Hz	1VII_/0JD
THD+N	_	-80	_	dB	1KHz/0dB
S/N	_	101	_	dB	10Kohm loading
Crosstalk	_	-80	_	dB	With A-Weighted Filter

Output Swing		0.45		Vrms	
					1KHz/-60dB
Dynamic Range		90		dB	10Kohm loading
					With A-Weighted Filter
DAC Output Power	_	4	_	mW	32ohm loading

2.7 ADC Characteristics

Table 2-7

Parameter	Min	Тур	Max	Unit	Test Conditions
Dynamic Range		92		dB	Fsample=44.1kHz Fin=1KHz 2mVpp Input
S/N	_ /	92	7 <u>4</u>	dB	E144 11-II-
THD+N	_ 1/	-75	7/_	dB	Fsample=44.1kHz
Crosstalk	_ /	-80	/ / _	dB	Fin=1KHz 1.2Vpp Input

2.8 BT Characteristics

2.8.1 Transmitter

Basic Data Rate

Table 2-8

Paramete	r	Min	Тур	Max	Unit	Test Conditions
RF Transmit P	ower		6	8	dBm	
RF Power Contro	l Range		20		dB	25℃,
20dB Bandw	idth		950	7	KHz	Power Supply
	+2MHz	7	-40	1	dBm	
Adjacent Channel	-2MHz	y.	-38		dBm	VBAT=5V
Transmit Power	+3MHz		-44		dBm	2441MHz
	-3MHz		-35		dBm	

Enhanced Data Rate

Table 2-9

Parameter		Min	Тур	Max	Unit	Test Conditions
Relative Power			-1		dB	
π/4 DQPSK	DEVM RMS		6		%	25℃,
	DEVM 99%		10		%	Power Supply
Modulation Accuracy	DEVM Peak		15		%	VBAT=5V
Adjacent Channel	+2MHz		-40		dBm	2441MHz
Transmit Power	-2MHz		-38		dBm	

+3MHz	-44	dBm
-3MHz	-35	dBm

2.8.2 Receiver

Basic Data Rate

Table 2-10

Paramete	Min	Тур	Max	Unit	Test Conditions	
Sensitivit	У		-94		dBm	
Co-channel Interferen	Co-channel Interference Rejection		-13		dB	
/	+1MHz		+5		dB	25℃,
	-1MHz		+2		dB	Power Supply
Adjacent Channel	+2MHz		+37		dB	VBAT=5V
Interference Rejection	-2MHz		+36		dB	2441MHz
	+3MHz		+40		dB	
	-3MHz	2	+35		dB	

Enhanced Data Rate

Table 2-11

Emanced Buta Rate			10 2 11			
Parameter		Min	Тур	Max	Unit	Test Conditions
Sensitivit	y		-94		dBm	
Co-channel Interferen	nce Rejection		-13		dB	
	+1MHz	Ĭ,	+5	Y	dB	25℃,
	-1MHz		+2		dB	Power Supply
Adjacent Channel	+2MHz	7/	+37	W.	dB	VBAT=5V
Interference Rejection	-2MHz		+36		dB	2441MHz
	+3MHz	1	+40		dB	1
	-3MHz		+35		dB	

2.8.3 BLE Transmitter

1M Data Rate

Table 2-12

Paramete	Parameter		Тур	Max	Unit	Test Conditions
Sensitivit	Sensitivity		-94		dBm	
RF Transmit Power			7	9	dB	25℃,
	+2MHz		-42	-20	dB	Power Supply
In-band Spurious	-2MHz		-34	-20	dB	
Emission	+3MHz		-46	-30	dB	VBAT=5V
	-3MHz		-36	-30	dB	2441MHz
Modulation	Δfl avg	225	247			

	Δf2 99%	185	236		
	Δf1avg/Δf2av	0.8	0.9		
Carrier Frequency Offset		-150	+/-10	+150	KHz
Frequency Drift		-50	+/-5	+50	KHz
Frequency Drift Rate		-20	3	+20	KHz/50us

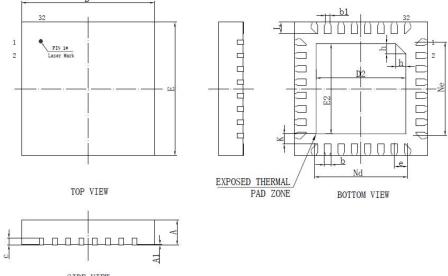
2M Data Rate

Table 2-13

ZM Data Rate		Table	2-13			
Paramete	er	Min	Тур	Max	Unit	Test Conditions
Sensitivit	Sensitivity		-94		dBm	
RF Transmit I	Power		7	9	dB	
	+2MHz		-46	-20	dB	
Adjacent Channel	-2MHz		-38	-20	dB	
Transmit	+3MHz	A	-53	-30	dB	25℃,
	-3MHz		-42	-30	dB	Power Supply
	Δfl avg	450	520			VBAT=5V
Frequency Deviation	Δf2 99%	370	500			2441MHz
	Δflavg/Δf2a	v 0.8	0.9			
Carrier Frequency Offset		-150	+/-10	+150	KHz	
Frequency Drift		-50	+/-5	+50	KHz	
Frequency Dri	ft Rate	-20	+/-3	+20	KHz/50us	

3. Package Information

3.1 QFN32_4.0x4.0



SYMBOL	M	ILLIMET	ER		
SIMBOL	MIN	NOM	MAX		
A	0.70	0.75	0.80		
A1	0	0.02	0.05		
ь	0.15	0.20	0. 25		
b1		0.14REF			
c	0. 203REF				
D	3. 90	4. 00	4.10		
D2	2.60	2.70	2.80		
e	0. 40BSC				
Nd		2. 80BSC			
E	3. 90	4. 00	4.10		
E2	2.60	2.70	2.80		
Ne	2. 80BSC				
L	0.30	0.35	0.40		
h	0. 25	0.30	0.35		
K	0. 30REF				

SIDE VIEW

Figure 3-1 JL6976M Package



Confidential

4. Revision History

Date	Revision	Description
2020.08.31	V1.0	Initial Release
	<u> </u>	

